NSN 5961-01-033-5575

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-033-5575 **Inclosure Material:** Metal **Overall Length:** Between 0.560 inches and 0.625 inches **Overall Diameter:** 0.420 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** -80.0 collector to base voltage/static/emitter open and -5.0 emitter to base voltage, static, collector open and -80.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** Between -0.25 amperes source cutoff current and -10.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector preset **Special Features:** Mtg flange included; junction pattern arrangement: pnp **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No